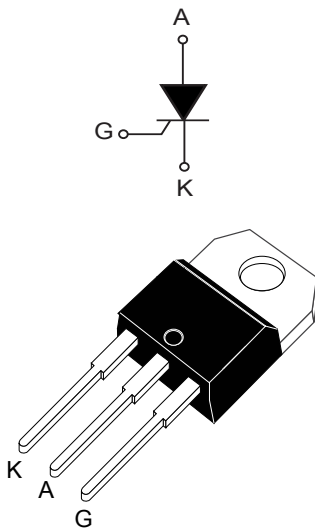


40 A 800 V high temperature SCR thyristors in insulated TO-220I package



TO-220AB insulated

Features

- High junction temperature: $T_j = 150\text{ }^{\circ}\text{C}$
- 800 V $V_{\text{DRM}} / V_{\text{RRM}}$
- 900 V $V_{\text{DSM}} / V_{\text{RSM}}$
- Low I_{GT} : 15 mA
- High static immunity $dV/dt = 1000\text{ V}/\mu\text{s}$ at $150\text{ }^{\circ}\text{C}$
- High turn-on rise dI/dt at $200\text{ A}/\mu\text{s}$
- Halogen-free molding, lead-free plating
- ECOPACK2 compliant
- Insulated package TO-220AB:
 - Insulated voltage: $2500\text{ V}_{\text{RMS}}$
 - Complies with UL 1554 (file ref. 81734)

Application

- Inrush current limiting circuits in AC/DC converters
- General purpose AC line load switching
- Heating resistor control, solid state relays

Description

Thanks to its junction temperature T_j up to $150\text{ }^{\circ}\text{C}$, the **TN4015H-8I** offers high thermal performance operation up to 40 A RMS in an insulated TO-220AB package. Its trade-off noise immunity ($dV/dt = 1000\text{ V}/\mu\text{s}$) versus its gate triggering current ($I_{\text{GT}} = 15\text{ mA}$) and its turn-on current rise ($dI/dt = 200\text{ A}/\mu\text{s}$) allow to design robust and compact control circuit in AC/DC converters for inrush current limiting circuits and industrial drives, such as overvoltage crowbar protection, motor control circuits and power tools.

Product status	
	TN4015H-8I

Product summary	
Order code	TN4015H-8I
Package	TO-220AB Ins.
$I_{\text{T(RMS)}}$	40 A
$V_{\text{DRM}}/V_{\text{RRM}}$	800 V
T_j (max.)	$150\text{ }^{\circ}\text{C}$

1 Characteristics

Table 1. Absolute maximum ratings (limiting values), $T_j = 25\text{ °C}$ unless otherwise specified

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (180 ° conduction angle)		$T_c = 92\text{ °C}$ 40	A
$I_{T(AV)}$	Average on-state current (180 ° conduction angle)		$T_c = 93\text{ °C}$ 25	A
			$T_c = 102\text{ °C}$ 22	
			$T_c = 108\text{ °C}$ 20	
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25 °C)		$t_p = 8.3\text{ ms}$ 440	A
			$t_p = 10\text{ ms}$ 400	
I^2t	I^2t value for fusing		$t_p = 10\text{ ms}$ 800	A ² s
di/dt	$I_G = 2 \times I_{GT}$, $tr \leq 100\text{ ns}$ Critical rate of rise of on-state current		$f = 50\text{ Hz}$ 200	A/ μ s
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage		$T_j = 150\text{ °C}$ 800	V
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage		$t_p = 10\text{ ms}$ 900	V
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu$ s	$T_j = 150\text{ °C}$ 4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ °C}$ 1	W
V_{RGM}	Maximum peak reverse gate voltage		5	V
T_{stg}	Storage junction temperature range		-40 to +150	°C
T_j	Maximum operating junction temperature		-40 to +150	°C
T_l	Maximum lead temperature soldering during 10 s		260	°C
V_{ins}	Insulation RMS voltage, 1 minute		2500	V

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$ unless otherwise specified)

Symbol	Test conditions		Value	Unit
I_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Min. 5	mA
			Max. 15	
V_{GT}			Max. 1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	$T_j = 150\text{ °C}$	Min. 0.2	V
I_H	$I_T = 500\text{ mA}$, gate open		Max. 50	mA
I_L	$I_G = 1.2 \times I_{GT}$		Max. 70	mA
dV/dt	$V_D = 536\text{ V}$, gate open	$T_j = 150\text{ °C}$	Min. 1000	V/ μ s
t_{gt}	$I_{TM} = 80\text{ A}$, $V_D = 536\text{ V}$, $I_G = 30\text{ mA}$, $(dI_G/dt)_{max} = 0.2\text{ A}/\mu$ s		Typ. 1.9	μ s
t_q	$I_T = 80\text{ A}$, $V_D = 536\text{ V}$, $V_R = 25\text{ V}$, $dV_D/dt = 40\text{ V}/\mu$ s		$T_j = 125\text{ °C}$ Typ. 70	μ s
			$T_j = 150\text{ °C}$ Typ. 85	μ s

Table 3. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 80\text{ A}$, $t_p = 380\text{ }\mu\text{s}$	$T_j = 25\text{ }^\circ\text{C}$	Max.	1.55	V
V_{TO}	Threshold voltage	$T_j = 150\text{ }^\circ\text{C}$	Max.	0.85	
R_D	Dynamic resistance	$T_j = 150\text{ }^\circ\text{C}$	Max.	9.5	m Ω
I_{DRM} , I_{RRM}	$V_D = V_{DRM} = V_{RRM}$	$T_j = 25\text{ }^\circ\text{C}$	Max.	2	μA
		$T_j = 150\text{ }^\circ\text{C}$		9	mA

Table 4. Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	Max.	1.6	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient	Typ.	60	

1.1 Characteristics (curves)

Figure 1. Maximum average power dissipation versus average on-state current

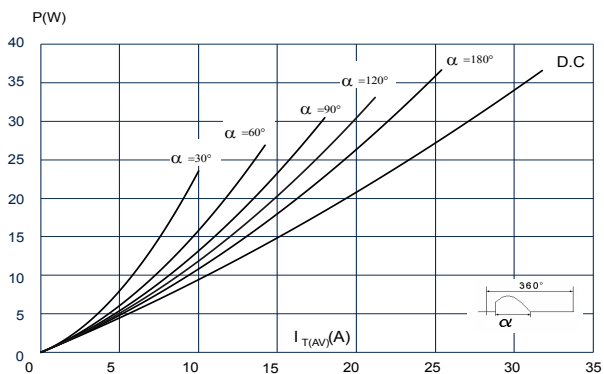


Figure 2. Average and DC on-state current versus case temperature

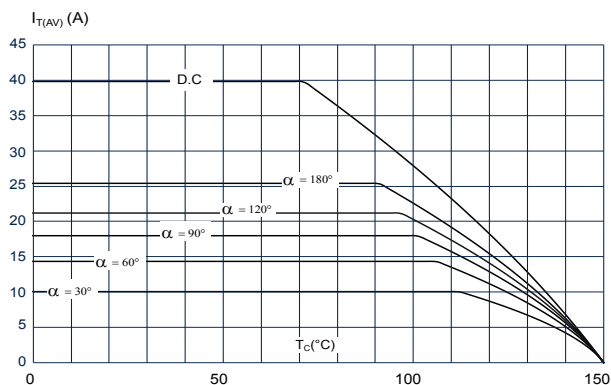


Figure 3. Average and D.C. on state current versus ambient temperature

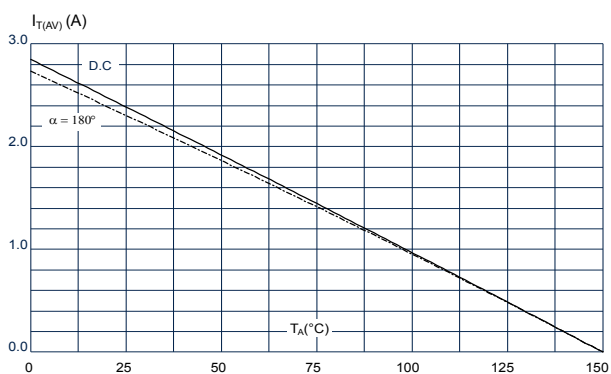


Figure 4. Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration

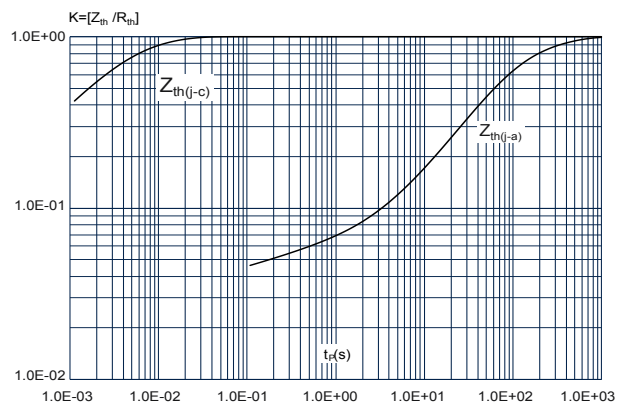


Figure 5. Relative variation of gate trigger current and gate voltage versus junction temperature

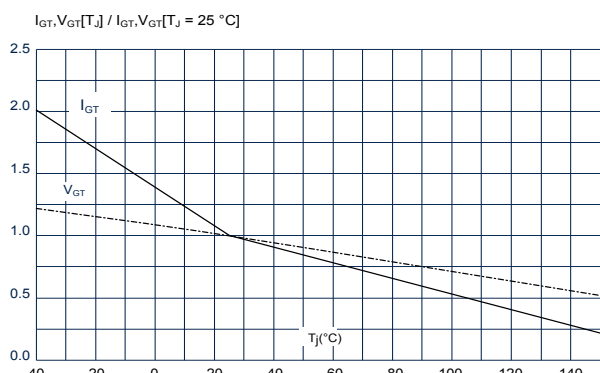


Figure 6. Relative variation of holding and latching current versus junction temperature

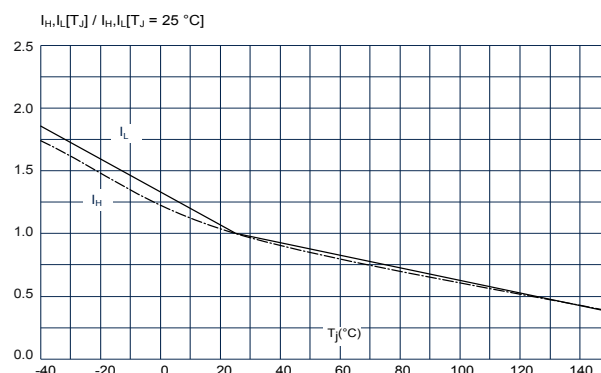
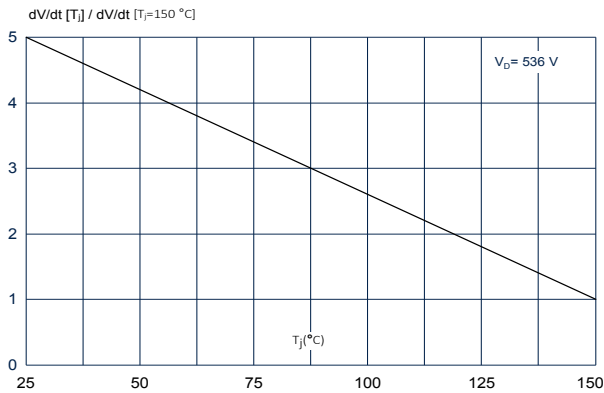
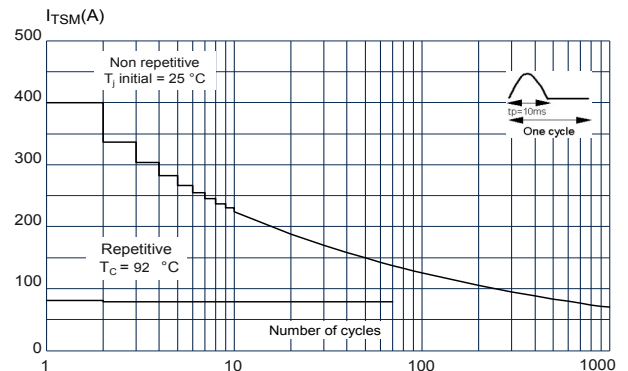
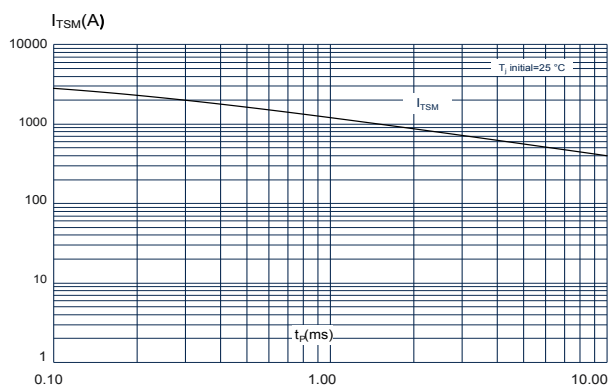
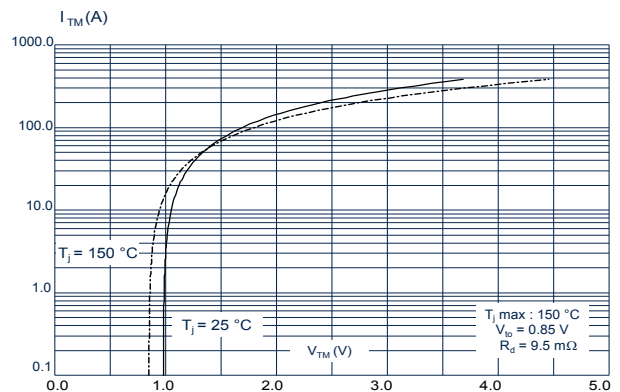
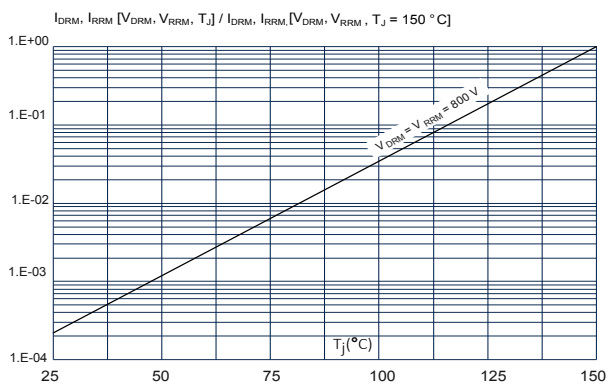
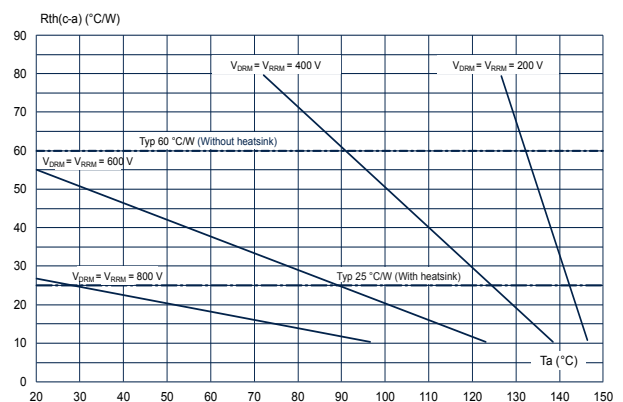


Figure 7. Relative variation of static dV/dt immunity versus junction temperature

Figure 8. Surge peak on-state current versus number of cycles

Figure 9. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ ms}$

Figure 10. On-state characteristics (maximum values)

Figure 11. Relative variation of leakage current versus junction temperature

Figure 12. Recommended maximum case-to-ambient thermal resistance versus ambient temperature for different peak off-state voltages


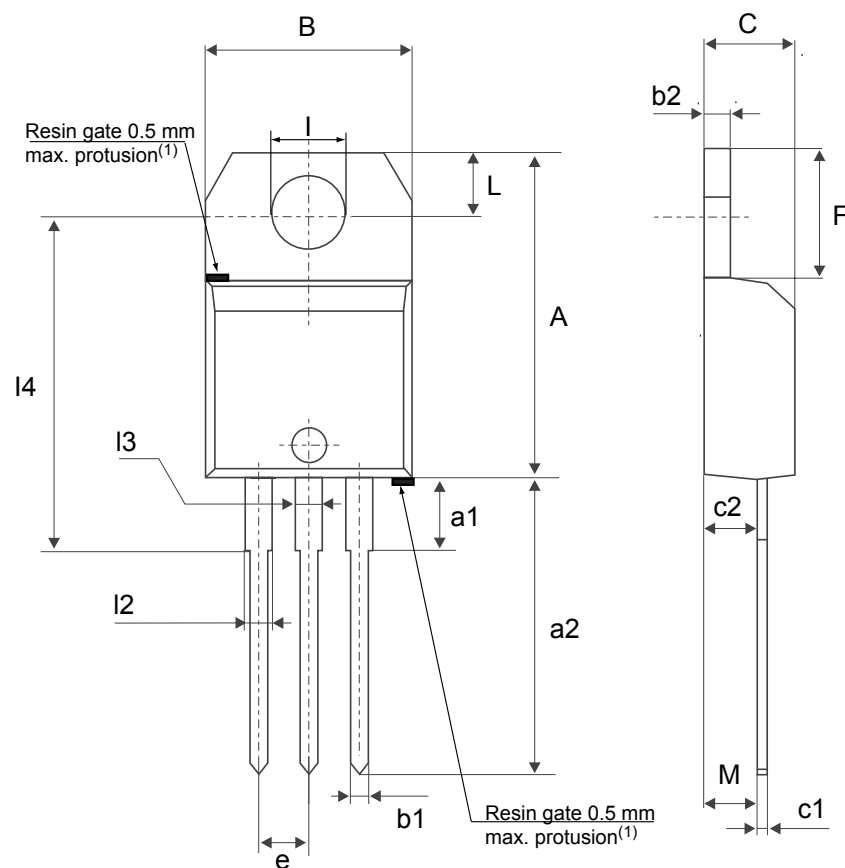
2 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-220AB insulated package information

- Molding compound resin is halogen-free and meets flammability standard UL94 level 0
- Lead-free package leads finishing
- **ECOPACK2** compliant
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 13. TO-220AB package outline



(1) Resin gate position accepted in one of the two positions or in the symmetrical opposites.

Table 5. TO-220AB package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0449		0.0669
l3	1.14		1.70	0.0449		0.0669
l4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. Inch dimensions are for reference only.

3 Ordering information

Figure 14. Ordering information scheme

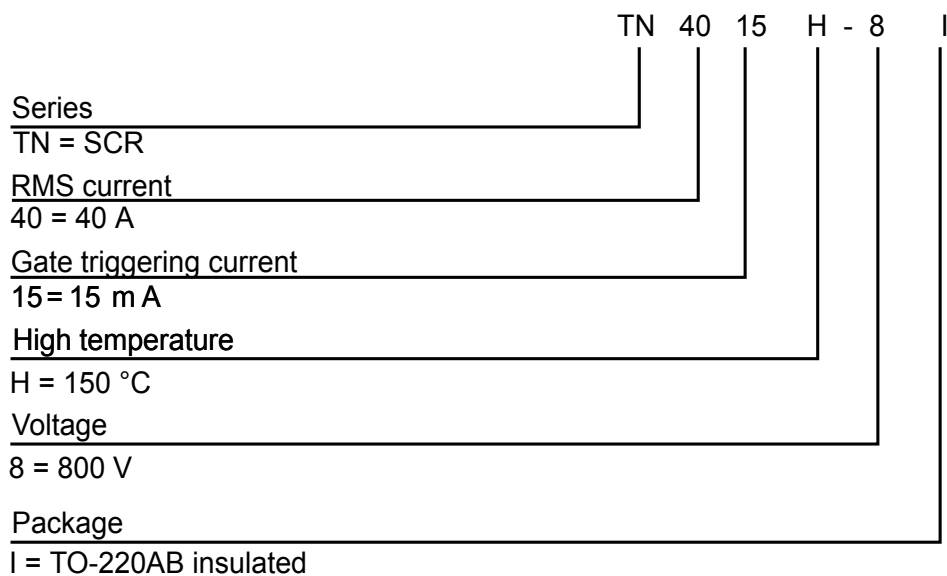


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN4015H-8I	TN4015H8I	TO-220AB ins.	1.9 g	50	Tube

Revision history

Table 7. Document revision history

Date	Revision	Changes
03-Apr-2025	1	Initial release.

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